NSN 5961-00-359-6812

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Inclosure Material	
inciosure material	:

Metal

Overall Length:

0.260 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.370 inches

Internal Configuration:

Junction contact

- Joint Electronic Device Engineering Council/jedec/case Outline Designation:
- To-5

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

4.0 emitter to base voltage, static, collector open and 40.0 collector to base voltage/static/emitter open and 30.0 collector to emitter voltage/static/base open

Current Rating Per Characteristic:

600.00 milliamperes source cutoff current

Power Rating Per Characteristic:

3.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Precious Material And Location:

Terminal surfaces gold

Precious Material:

Gold

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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